

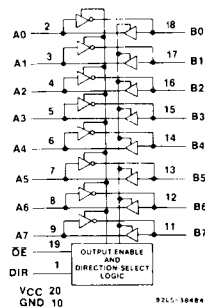
CD54HC643/3A CD54HCT643/3A Octal Bus Transceiver, 3-State, True/Inverting

The RCA-CD54HC643 and CD54HCT643 silicon-gate CMOS 3-state bidirectional buffers are intended for two-way asynchronous communication between data buses. They have high drive current outputs which enable high-speed operation when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuits and have speeds comparable to low-power Schottky TTL circuits. They can drive 15 LSTTL loads.

The CD54HC643 and CD54HCT643 are true/inverting buffers.

The direction of data flow (A to B, B to A) is controlled by the DIR input.

Outputs are enabled by a low on the Output Enable input (OE); a high OE puts these devices in the high impedance mode.



Package Specifications

See Section 11, Fig. 13

FUNCTIONAL DIAGRAM

Static Electrical Characteristics (Limits with black dots (•) are tested 100%) — Bus Type

CHARACTERISTICS	TEST CONDITIONS									UNITS	
	V _{DD}	HC/HCT				V _{IN}		LIMITS			
		V _O	I _O	V _{CC} or GND	HC V _{IL} or V _{IH}	HCT V _{IL} or V _{IH}	MIN.	MAX.			
Output High (Source) Current I _{OH} Min. - TTL Load	25°C	4.5	3.98	—	—	0, 4.5	0, 4.5	-6•	—	mA	
	-55°C	4.5	3.70	—	—	0, 4.5	0, 4.5	-6•	—		
	+125°C	4.5	3.70	—	—	0, 4.5	0, 4.5	-6•	—		
Output Low (Sink) Current I _{OL} Min. - TTL Load	25°C	4.5	0.26	—	—	0, 4.5	0, 4.5	6•	—	mA	
	-55°C	4.5	0.40	—	—	0, 4.5	0, 4.5	6•	—		
	+125°C	4.5	0.40	—	—	0, 4.5	0, 4.5	6•	—		
High Level Output Voltage V _{OH} - TTL Load	25°C	4.5	—	-6	—	1.35, 3.15	0.8, 2.0	3.98•	—	V	
	-55°C	4.5	—	-6	—	1.35, 3.15	0.8, 2.0	3.70•	—		
	+125°C	4.5	—	-6	—	1.35, 3.15	0.8, 2.0	3.70•	—		
Low Level Output Voltage V _{OL} - TTL Load	25°C	4.5	—	6	—	1.35, 3.15	0.8, 2.0	—	0.26•	V	
	-55°C	4.5	—	6	—	1.35, 3.15	0.8, 2.0	—	0.40•		
	+125°C	4.5	—	6	—	1.35, 3.15	0.8, 2.0	—	0.40•		
Quiescent Device Current I _{CC}	25°C	6	—	—	6, 0	—	—	—	8•	μA	
	-55°C	6	—	—	6, 0	—	—	—	160•		
	+125°C	6	—	—	6, 0	—	—	—	160•		

The complete static electrical test specification consists of the above by-type static tests combined with the standard static tests in the beginning of this section.

CD54HC643/3A

CD54HCT643/3A

HCT INPUT LOADING TABLE

INPUT	UNIT LOAD*
DIR	0.9
OE, A	1.5
B	0.4

*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 360 μ A max. @ 25°C.

Switching Speed

(Limits with black dots (•) are tested 100%.)

SWITCHING CHARACTERISTICS ($C_L = 50$ pF, Input $t_r, t_f = 6$ ns)

CHARACTERISTIC	SYMBOL	V_{CC} V	25°C				-55°C to +125°C				UNITS	
			HC		HCT		54HC		54HCT			
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.		
Propagation Delay A → \bar{B} B → \bar{A}	t_{PLH}	2	—	90	—	—	—	—	135	—	—	ns
		4.5	—	18	—	22	—	27	—	33		
		6	—	15	—	—	—	23	—	—		
B → A	t_{PHL}	2	—	110	—	—	—	165	—	—		
		4.5	—	22•	—	26•	—	33•	—	39•		
		6	—	19	—	—	—	28	—	—		
Output High Z: To High Level To Low Level	t_{PZH} t_{PZL}	2	—	150	—	—	—	225	—	—		
		4.5	—	30•	—	33•	—	45•	—	50•		
		6	—	26	—	—	—	38	—	—		
Output High Level Output Low Level to High Z	t_{PHZ} t_{PLZ}	2	—	150	—	—	—	225	—	—		
		4.5	—	30•	—	30•	—	45•	—	45•		
		6	—	26	—	—	—	38	—	—		
Output Transition Time	t_{TLH} t_{THL}	2	—	60	—	—	—	90	—	—		
		4.5	—	12	—	12	—	18	—	18		
		6	—	10	—	—	—	15	—	—		
Input Capacitance	C_i	—	—	10	—	10	—	10	—	10	pF	
3-State Output Capacitance	C_o	—	—	20	—	20	—	20	—	20		

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Burn-In Test-Circuit Connections

(Use Static II for /3A burn-in and Dynamic for Life Test.)

Static	STATIC BURN-IN I			STATIC BURN-IN II		
	OPEN	GROUND	V_{CC} (6V)	OPEN	GROUND	V_{CC} (6V)
CD54HC/HCT643	2-9	1,10-19	20	—	10	1-9,11-18,19,20
Dynamic	OPEN	GROUND	1/2 V_{CC} (3V)	V_{CC} (6V)	OSCILLATOR	
CD54HC/HCT643	—	10	11-18	1,20	50 kHz	25 kHz
					2-9	19

NOTE: Each pin except V_{CC} and Gnd will have a resistor of 2k-47k ohms.